

DATA SHEET

74LVT623

**3.3 V octal transceiver with dual enable,
non-inverting (3-State)**

Product specification
Supersedes data of 1999 Jul 09
File under Integrated Circuits, IC24 Handbook

2001 Mar 12

3.3 V octal transceiver with dual enable, non-inverting (3-State)

74LVT623

FEATURES

- Separate controls for data flow in each direction
- Output capability: +64 mA/-32 mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- No bus current loading when output is tied to 5 V bus
- Power-up 3-State
- Power-up reset
- Latch-up protection exceeds 500 mA per JEDEC Std 17
- ESD protection exceeds 2000 V per MIL STD 883 Method 3015 and 200 V per Machine Model

DESCRIPTION

The 74LVT623 is a high-performance BiCMOS product designed for V_{CC} operation at 3.3 V.

The 74LVT623 device is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The 74LVT623 is designed for asynchronous two-way communication between data buses. The control function implementation allows for maximum flexibility in timing. This device allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending upon the logic levels at the Enable inputs (\overline{OEBA} and OEAB). The Enable inputs can be used to disable the device so that the buses are effectively isolated.

Control of data flow from B to A is similar, but using the \overline{EBA} , \overline{LEBA} , and OEBA inputs.

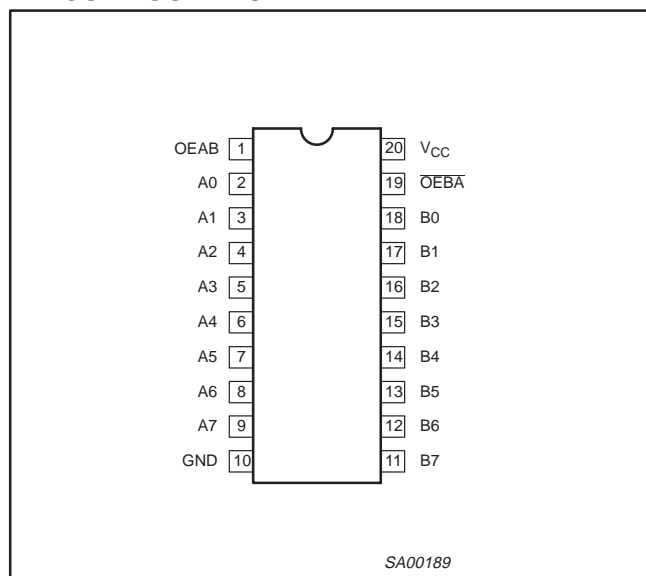
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25\text{ }^{\circ}\text{C}; \text{GND} = 0\text{ V}$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay An to Bn or Bn to An	$C_L = 50\text{ pF};$ $V_{CC} = 3.3\text{ V}$	2.3 2.5	ns
C_{IN}	Input capacitance	$V_I = 0\text{ V or } 3.0\text{ V}$	4	pF
$C_{I/O}$	I/O capacitance	Outputs disabled; $V_{I/O} = 0\text{ V or } 3.0\text{ V}$	7	pF
I_{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6\text{ V}$	0.13	mA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	TYPE NUMBER	DWG NUMBER
20-Pin Plastic SO	-40 °C to +85 °C	74LVT623D	SOT163-1
20-Pin Plastic SSOP Type II	-40 °C to +85 °C	74LVT623DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40 °C to +85 °C	74LVT623PW	SOT360-1

PIN CONFIGURATION



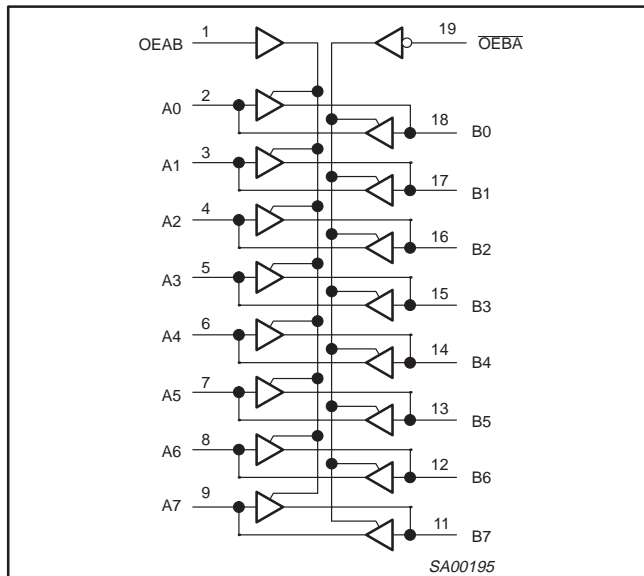
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	OEAB	Output enable input, A side to B side (active-High)
2, 3, 4, 5, 6, 7, 8, 9	A0 – A7	Data inputs/outputs (A side)
18, 17, 16, 15, 14, 13, 12, 11	B0 – B7	Data inputs/outputs (B side)
19	\overline{OEBA}	Output enable input, B side to A side (active-Low)
10	GND	Ground (0 V)
20	V_{CC}	Positive supply voltage

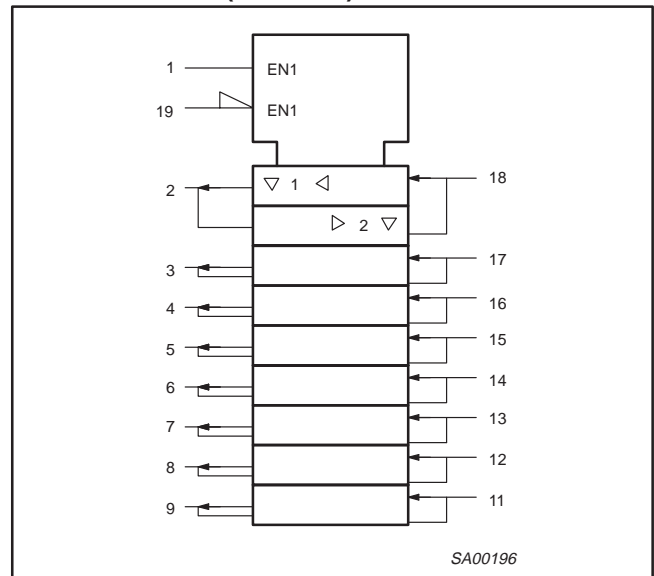
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LOGIC SYMBOL



LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

INPUTS		INPUTS/OUTPUTS	
OEBA	OEAB	An	Bn
L	L	An = Bn	Inputs
H	H	Inputs	Bn = An
H	L	Z	Z
L	H	An = Bn	Bn = An

H = High voltage level
 L = Low voltage level
 Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V _I < 0	-50	mA
V _I	DC input voltage ³		-0.5 to +7.0	V
I _{OK}	DC output diode current	V _O < 0	-50	mA
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
I _{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	-64	
T _{stg}	Storage temperature range		-65 to +150	°C

NOTES:

- Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150 °C.
- The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Low-level input voltage		0.8	V
I_{OH}	High-level output current		-32	mA
I_{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle $\leq 50\%$; $f \geq 1$ kHz		64	
$\Delta t/\Delta v$	Input transition rise or fall rate; outputs enabled		10	ns/V
T_{amb}	Operating free-air temperature range	-40	+85	$^{\circ}\text{C}$

DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNIT
			Temp = -40°C to $+85^{\circ}\text{C}$			
			MIN	TYP ¹	MAX	
V_{IK}	Input clamp voltage	$V_{CC} = 2.7\text{ V}; I_{IK} = -18\text{ mA}$		-0.9	-1.2	V
V_{OH}	High-level output voltage	$V_{CC} = 2.7$ to $3.6\text{ V}; I_{OH} = -100\ \mu\text{A}$	$V_{CC}-0.2$	$V_{CC}-0.1$		V
		$V_{CC} = 2.7\text{ V}; I_{OH} = -8\text{ mA}$	2.4	2.5		
		$V_{CC} = 3.0\text{ V}; I_{OH} = -32\text{ mA}$	2.0	2.2		
V_{OL}	Low-level output voltage	$V_{CC} = 2.7\text{ V}; I_{OL} = 100\ \mu\text{A}$		0.1	0.2	V
		$V_{CC} = 2.7\text{ V}; I_{OL} = 24\text{ mA}$		0.3	0.5	
		$V_{CC} = 3.0\text{ V}; I_{OL} = 16\text{ mA}$		0.25	0.4	
		$V_{CC} = 3.0\text{ V}; I_{OL} = 32\text{ mA}$		0.3	0.5	
		$V_{CC} = 3.0\text{ V}; I_{OL} = 64\text{ mA}$		0.4	0.55	
V_{RST}	Power-up output low voltage ⁵	$V_{CC} = 3.6\text{ V}; I_O = 1\text{ mA}; V_I = \text{GND or } V_{CC}$		0.13	0.55	V
I_I	Input leakage current	$V_{CC} = 3.6\text{ V}; V_I = V_{CC}$ or GND	Control pins	± 0.1	± 1	μA
		$V_{CC} = 0$ or $3.6\text{ V}; V_I = 5.5\text{ V}$		1	10	
		$V_{CC} = 3.6\text{ V}; V_I = 5.5\text{ V}$	I/O Data pins ⁴	1	20	
		$V_{CC} = 3.6\text{ V}; V_I = V_{CC}$		0.1	1	
		$V_{CC} = 3.6\text{ V}; V_I = 0$		-1	-5	
I_{OFF}	Output off current	$V_{CC} = 0\text{ V}; V_I$ or $V_O = 0$ to 4.5 V		1	± 100	μA
I_{HOLD}	Bus Hold current A or B ports	$V_{CC} = 3\text{ V}; V_I = 0.8\text{ V}$	75	150		μA
		$V_{CC} = 3\text{ V}; V_I = 2.0\text{ V}$	-75	-150		
I_{EX}	Current into an output in the High state when $V_O > V_{CC}$	$V_O = 5.5\text{ V}; V_{CC} = 3.0\text{ V}$		60	125	μA
$I_{PU/PD}$	Power up/down 3-State output current ³	$V_{CC} \leq 1.2\text{ V}; V_O = 0.5\text{ V}$ to $V_{CC}; V_I = \text{GND or } V_{CC}; \text{OE/OE} = \text{Don't care}$		15	± 100	μA
I_{CCH}	Quiescent supply current	$V_{CC} = 3.6\text{ V}; \text{Outputs High}, V_I = \text{GND or } V_{CC}, I_O = 0$		0.13	0.19	mA
I_{CCL}		$V_{CC} = 3.6\text{ V}; \text{Outputs Low}, V_I = \text{GND or } V_{CC}, I_O = 0$		3	12	
I_{CCZ}		$V_{CC} = 3.6\text{ V}; \text{Outputs Disabled}; V_I = \text{GND or } V_{CC}, I_O = 0$		0.13	0.19	
ΔI_{CC}	Additional supply current per input pin ²	$V_{CC} = 3\text{ V}$ to $3.6\text{ V}; \text{One input at } V_{CC} - 0.6\text{ V}, \text{Other inputs at } V_{CC}$ or GND		0.1	0.2	mA

NOTES:

- All typical values are at $V_{CC} = 3.3\text{ V}$ and $T_{amb} = 25^{\circ}\text{C}$.
- This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
- This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 msec . From $V_{CC} = 1.2\text{ V}$ to $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ a transition time of $100\ \mu\text{sec}$ is permitted. This parameter is valid for $T_{amb} = 25^{\circ}\text{C}$ only.
- Unused pins at V_{CC} or GND.
- For valid test results, data must not be loaded into the flip-flops (or latches) after applying the power.

3.3 V octal transceiver with dual enable, non-inverting (3-State)

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AC CHARACTERISTICS

GND = 0 V, $t_R = t_F = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω ; $T_{amb} = -40$ °C to $+85$ °C.

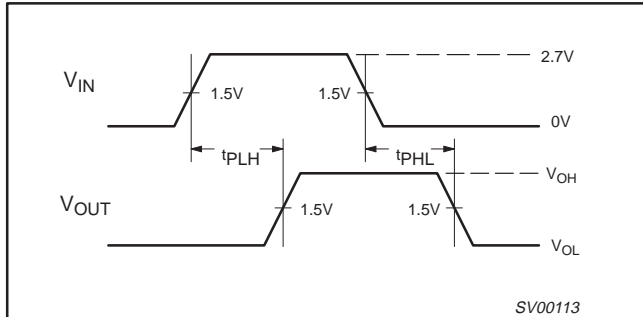
SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			$V_{CC} = 3.3$ V ± 0.3 V		$V_{CC} = 2.7$ V		
			MIN	TYP ¹	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay An to Bn, Bn to An	1	1.0 1.0	2.3 2.5	3.5 3.7	4.3 4.1	ns
t_{PZH} t_{PZL}	Output enable time OEBA to An	2 3	1.0 1.1	3.7 3.7	5.9 5.9	7.6 6.8	ns
t_{PHZ} t_{PLZ}	Output disable time OEBA to An	2 3	1.8 1.8	3.6 3.2	5.0 4.5	5.5 4.6	ns
t_{PZH} t_{PZL}	Output enable time OEAB to Bn	2 3	1.0 1.4	4.2 4.3	6.3 6.2	7.8 6.9	ns
t_{PHZ} t_{PLZ}	Output disable time OEAB to Bn	2 3	2.3 2.0	3.9 3.6	6.1 5.3	6.9 5.8	ns

NOTE:

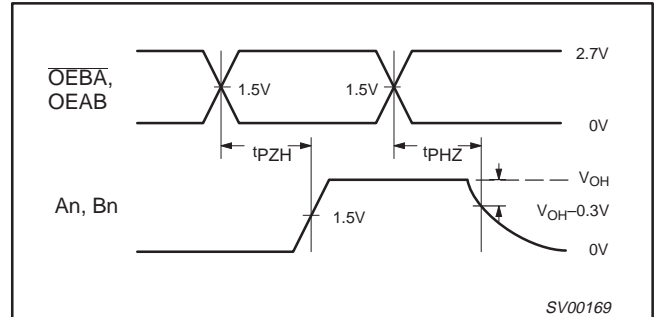
1. All typical values are at $V_{CC} = 3.3$ V and $T_{amb} = 25$ °C.

AC WAVEFORMS

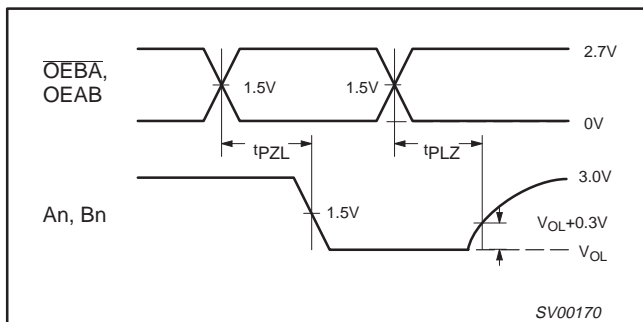
$V_M = 1.5$ V, $V_{IN} =$ GND to 2.7 V



Waveform 1. Propagation Delay for Non-Inverting Output



Waveform 2. 3-State Output Enable Time to High Level and Output Disable Time from High Level

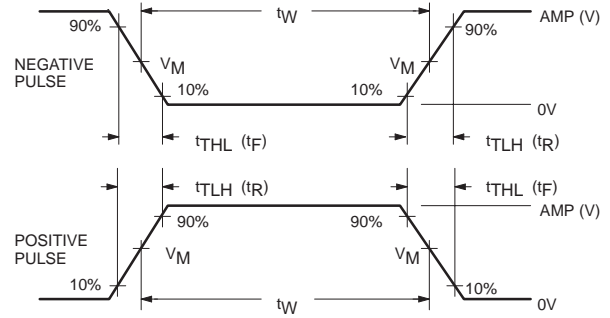
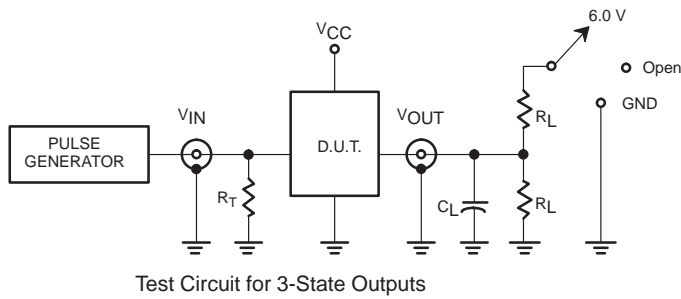


Waveform 3. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

3.3 V octal transceiver with dual enable, non-inverting (3-State)

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TEST CIRCUIT AND WAVEFORM



SWITCH POSITION

TEST	SWITCH
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6V
t_{PHZ}/t_{PZH}	GND

DEFINITIONS

R_L = Load resistor; see AC CHARACTERISTICS for value.

C_L = Load capacitance includes jig and probe capacitance; see AC CHARACTERISTICS for value.

R_T = Termination resistance should be equal to Z_{OUT} of pulse generators.

FAMILY	INPUT PULSE REQUIREMENTS				
	Amplitude	Rep. Rate	t_W	t_R	t_F
74LVT	2.7 V	$\leq 10\text{ MHz}$	500 ns	$\leq 2.5\text{ ns}$	$\leq 2.5\text{ ns}$

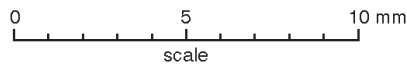
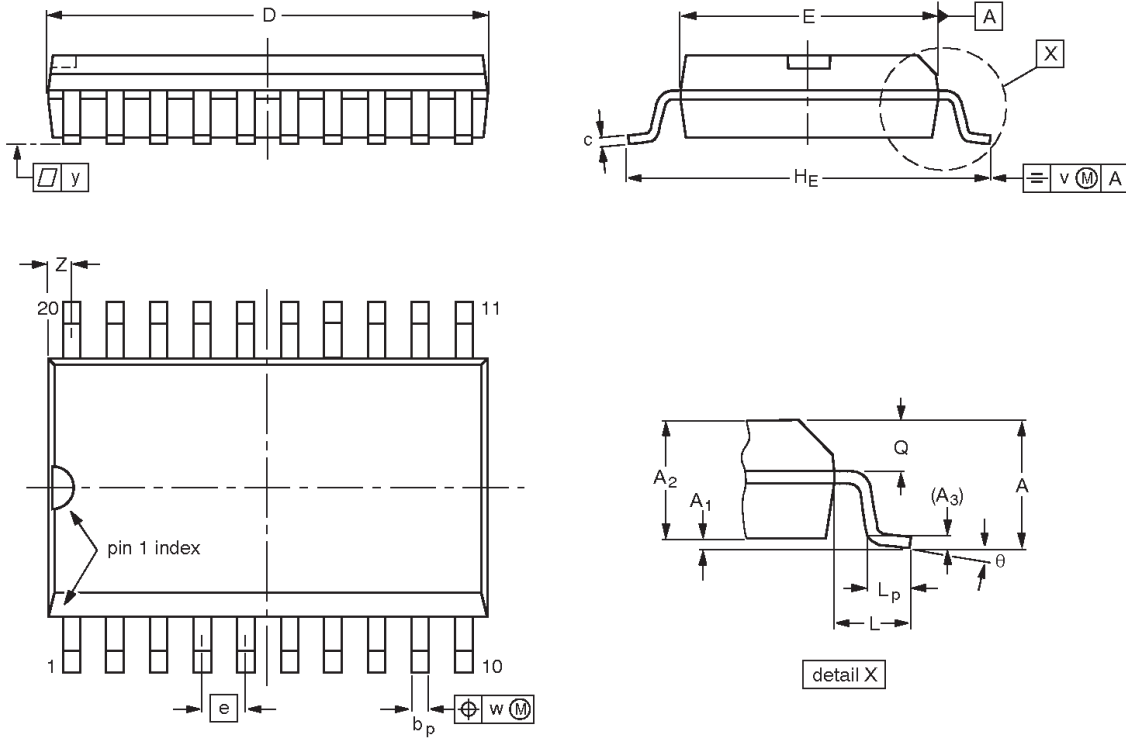
SV00092

3.3 V octal transceiver with dual enable, non-inverting (3-State)

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	HE	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	2.65	0.30 0.10	2.45 2.25	0.25	0.49 0.36	0.32 0.23	13.0 12.6	7.6 7.4	1.27	10.65 10.00	1.4	1.1 0.4	1.1 1.0	0.25	0.25	0.1	0.9 0.4	8° 0°
inches	0.10	0.012 0.004	0.096 0.089	0.01	0.019 0.014	0.013 0.009	0.51 0.49	0.30 0.29	0.050	0.419 0.394	0.055	0.043 0.016	0.043 0.039	0.01	0.01	0.004	0.035 0.016	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

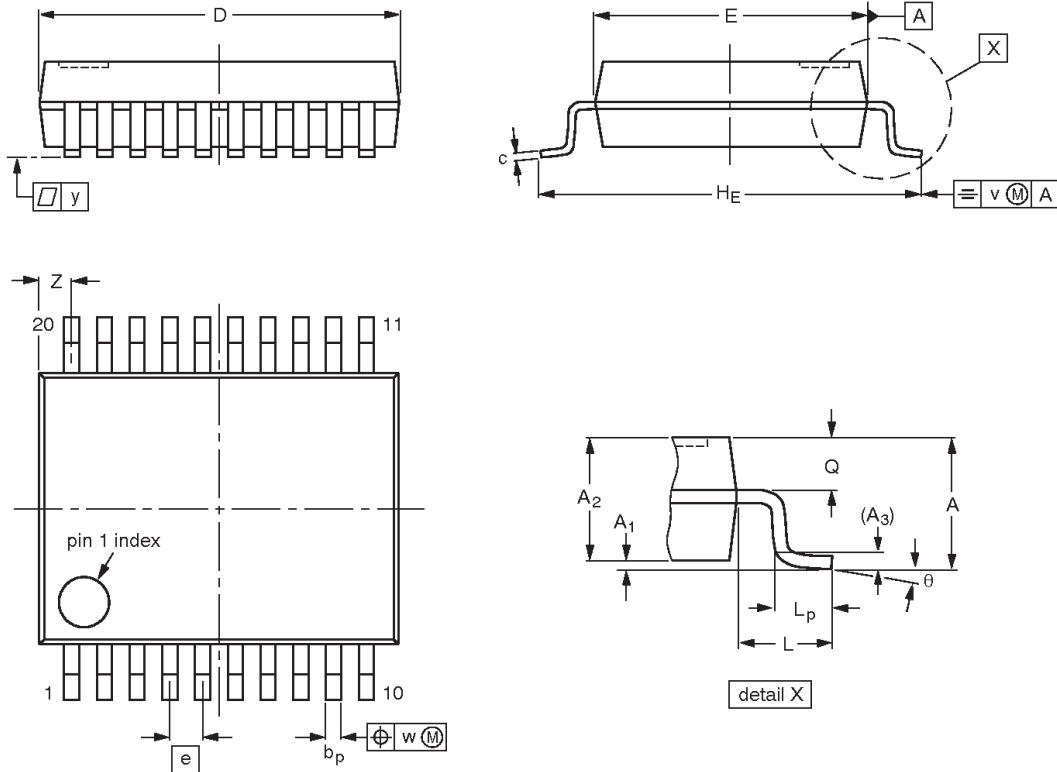
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT163-1	075E04	MS-013				97-05-22 99-12-27

3.3 V octal transceiver with dual enable, non-inverting (3-State)

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	2.0	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

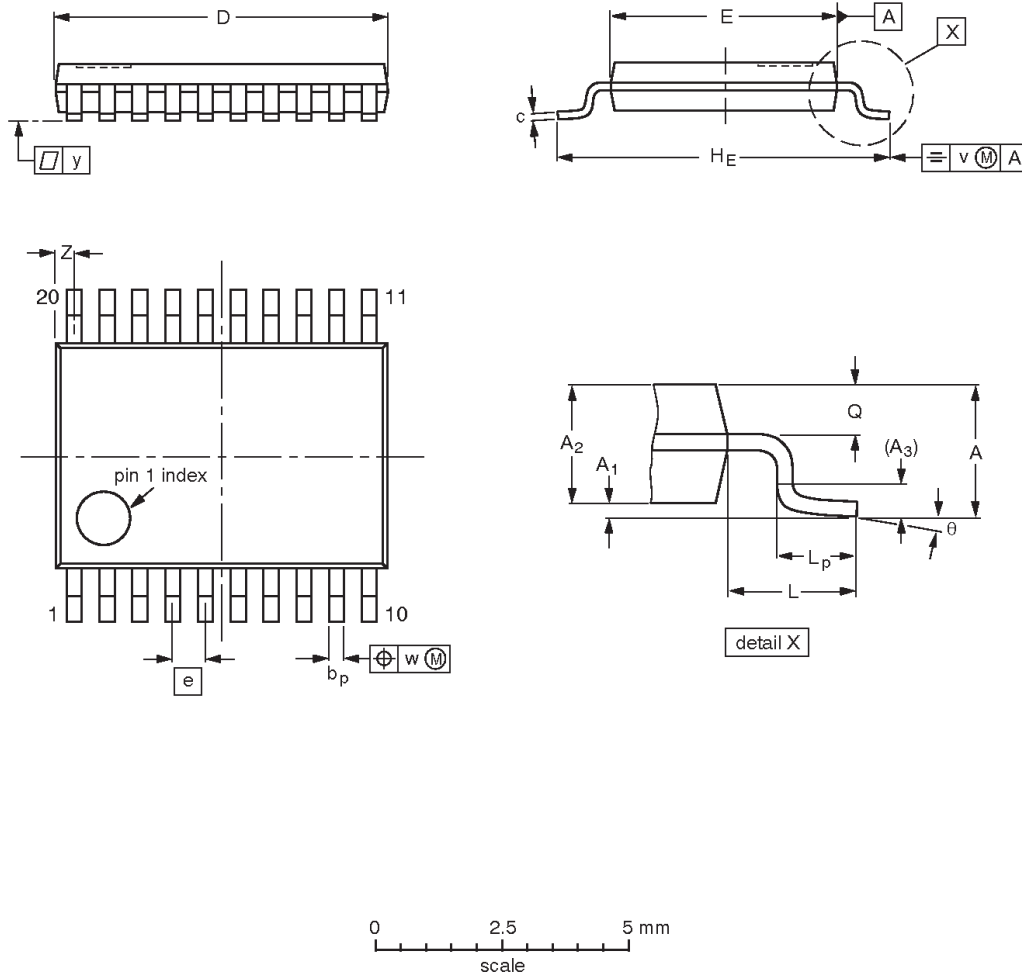
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT339-1		MO-150				95-02-04 99-12-27

3.3 V octal transceiver with dual enable, non-inverting (3-State)

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TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽²⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.10	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.5 0.2	8° 0°

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT360-1		MO-153				95-02-04 99-12-27

3.3 V octal transceiver with dual enable, non-inverting (3-State)

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Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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